



SD103AW

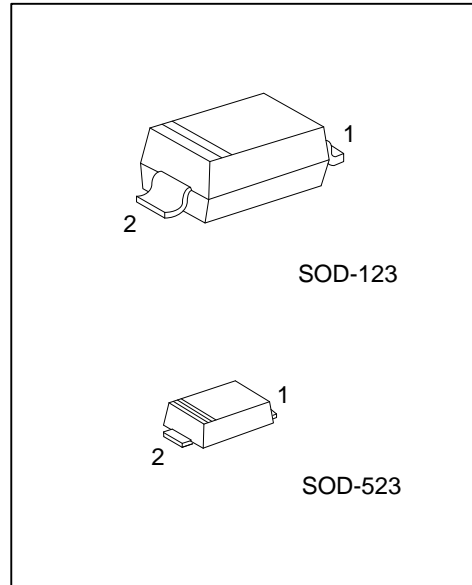
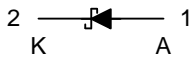
DIODE

SCHOTTKY BARRIER SWITCHING DIODE

FEATURES

- * Low Forward Voltage Drop
- * Fast Switching
- * Negligible Reverse Recovery Time
- * Low Reverse Capacitance
- * Designed for Surface Mount Application
- * PN Junction Guard Ring for Transient and ESD Protection

SYMBOL



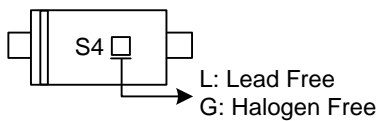
ORDERING INFORMATION

Order Number		Package	Pin Assignment		Packing
Lead Free	Halogen Free		1	2	
SD103AWL-CA2-R	SD103AWG-CA2-R	SOD-123	A	K	Tape Reel
SD103AWL-CC2-R	SD103AWG-CC2-R	SOD-523	A	K	Tape Reel

Note: Pin Assignment: A: Anode K: Cathode

<p>SD103AWG-CA2-R</p> <ul style="list-style-type: none"> (1) Packing Type (2) Package Type (3) Green Package 	<ul style="list-style-type: none"> (1) R: Tape Reel (2) CA2: SOD-123, CC2: SOD-523 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING



■ **ABSOLUTE MAXIMUM RATINGS** (Single Diode @ $T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Maximum repetitive Peak Reverse Voltage	V_{RRM}	40	V
Maximum DC Blocking Voltage	V_R	40	V
Working Peak Reverse Voltage	V_{RWM}	40	V
Maximum RMS Reverse Voltage	$V_{R(RMS)}$	28	V
Forward Continuous Current	I_{FM}	350	mA
Non-Repetitive Peak Forward Current at $t_p \leq 1.0\text{s}$	I_{FSM}	1.5	A
Power Dissipation	P_D	400	mW
Storage Temperature	T_{STG}	-65 ~ +125	$^{\circ}\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

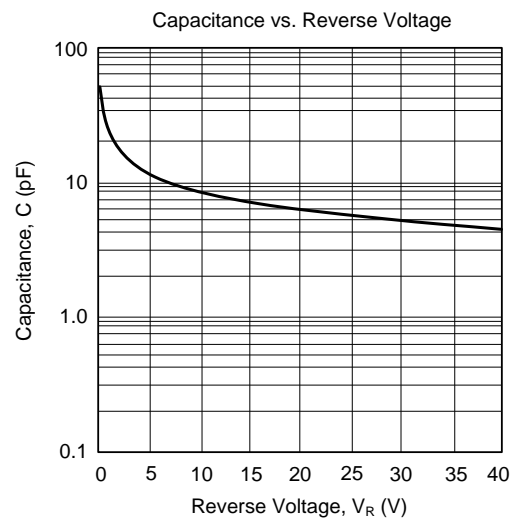
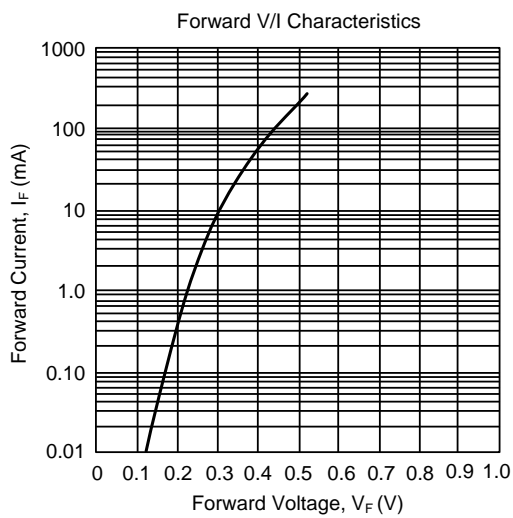
■ **THERMAL DATA**

PARAMETER	SYMBOL	RATINGS	UNIT
Thermal Resistance Junction to Ambient	θ_{JA}	300	$^{\circ}\text{C/W}$

■ **ELECTRICAL CHARACTERISTICS** ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage Drop	V_F	$I_F=20\text{mA}$			0.37	V
		$I_F=200\text{mA}$			0.60	V
Reverse Breakdown Voltage	BV_R	$I_R=10\mu\text{A}$	40			V
Peak Reverse Leakage Current	I_{RM}	$V_R=30\text{V}$			5.0	μA
Typical Reverse Recovery Time	t_{RR}	$I_F=I_R=50\sim 200\text{mA}$, $R_L=100\Omega$ recover to $0.1 \times I_R$		10		ns
Typical Junction Capacitance	C_T	$V_R=0\text{V}$, $f=1.0\text{MHz}$		50		pF

■ TYPICAL CHARACTERISTICS



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